## NSN 5961-01-370-1945

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Internal Configuration:
Junction contact
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
3.5 breakdown voltage, emitter-to-base, collector open and 65.0 breakdown voltage, collector-to-emitter, with base short-circuited to
emitter and 25.0 breakdown voltage, collector-to-emitter, base open and 65.0 breakdown voltage, collector-to-base, emitter open
Current Rating Per Characteristic:
10.00 milliamperes zero-gate-voltage source current preset
Power Rating Per Characteristic:
200.0 watts large-signal output power, common-collector universal
Transfer Ratio:
5.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0